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Total Number of Pages: 02  B.Tech BE2101  2 <sup>nd</sup> Semester Back Examination 2017-18  BASIC ELECTRONICS  BRANCH: AEIE, AERO, AUTO, BIOMED, BIOTECH, CHEM, CIVIL, CSE, ECE, EEE, EIE, ELECTRICAL, ENV, ETC, FASHION, FAT, IEE, IT, ITE, MANUFAC, MANUTECH, MARINE, MECH, METTA, METTAMIN, MINERAL, MINING, MME, PE, PLASTIC, TEXTILE															
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Q1	a) b) c) d) e) f) g) h) i)	Answer the following questions:  What is the meaning of CMRR of an Op-amp?  Write down the advantages of a negative feedback amplifier.  Derive the expression for collector current for a CE transistor.  The gain of a certain amplifier is 30dB. Express it numerically.  Write down the four applications of a diode.  Realize a NOR gate from NAND gate.  Convert the decimal number -32 to its equivalent and 2's complement form.  How BJT acts as a switch?  State the characteristics of an ideal op-amp.  Draw the block diagram of a 8X1 MUX.								(2 x 10)					
Q2	a) b)	Explain the control output wavef	operat		-	•								input-	(5) (5)
Q3	a) b)	Draw circuits for both inverting and non-inverting amplifier using op-amp. Derive the expression for the gain of an inverting amplifier.  Draw the block diagram of function generator and explain its operation.							(7) (3)						
Q4	a) b)	What are the oscillation ar What is the voltmeter.	nd also	the o	condi	tion o	f osci	llatior	in a	RC pl	nase	shift o	scillat	or.	(5) (5)

The open loop gain of an amplifier changes by 5%. If 10dB negative feedback is applied, calculate percentage change of the closed loop gain?

What is active, saturation and cut-off region of a transistor? Explain with

Q5 a)

b)

necessary diagram.

Q6	a)	Implement the following function using NOR gate only $F(A, B, C, D) = (A+C) (B+D)$ .							
	b)	Draw the physical structure, drain characteristics, transfer characteristics and circuit symbol of an n-channel depletion type MOSFET.							
Q7		A crystal diode having an internal resistance $r_i$ =10 $\Omega$ is used for center tapped full wave rectification. If the applied voltage is V=50 sin( $\pi$ t) and the load resistance is $R_L$ = 1K $\Omega$ , determine the followings i) Draw the input and output voltage and current waveforms ii) The efficiency of the circuit. iii) The ripple factor.	(10)						
Q8		Write short answer on any TWO :	(5 x 2)						
	a)	CRT							
	b)	SR Flip-Flop							
	c)	Zener diode as voltage regulator							
	d)	Static and Dynamic Memories							